

## KSE13006/13007

## **High Voltage Switch Mode Application**

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



1.Base 2.Collector 3.Emitter

### **NPN Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter		Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	: KSE13006	600	V
		: KSE13007	700	V
$V_{CEO}$	Collector-Emitter Voltage	: KSE13006	300	V
		: KSE13007	400	V
V <sub>EBO</sub>	Emitter- Base Voltage		9	V
I <sub>C</sub>	Collector Current (DC)		8	Α
I <sub>CP</sub>	Collector Current (Pulse)		16	Α
I <sub>B</sub>	Base Current		4	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)		80	W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector- Emitter Breakdown Voltage : KSE13006 : KSE13007	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	300 400			V V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	mA
h <sub>FE</sub>	*DC Current Gain	$V_{CE} = 5V, I_{C} = 2A$ $V_{CE} = 5V, I_{C} = 5A$	8 5		60 30	
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$ $I_C = 5A, I_B = 1A$ $I_C = 8A, I_B = 2A$			1 2 3	V V V
V <sub>BE</sub> (sat)	*Base-Emitter Saturation Voltage	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.4A I <sub>C</sub> = 5A, I <sub>B</sub> = 1A			1.2 1.6	V V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 0.1MHz		110		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
t <sub>ON</sub>	Turn On Time	$V_{CC} = 125V, I_{C} = 5A$			1.6	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 1A$			3	μs
t <sub>F</sub>	Fall Time	$R_L = 50\Omega$			0.7	μs

<sup>\*</sup> Pulse test: PW≤300μs, Duty cycle≤2%

## **Typical Characteristics**

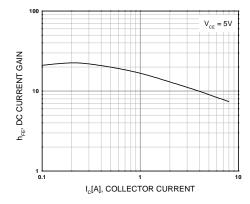


Figure 1. DC current Gain

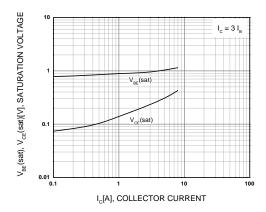


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

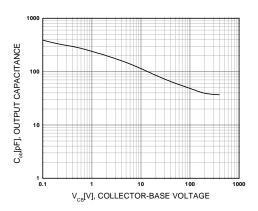


Figure 3. Collector Output Capacitance

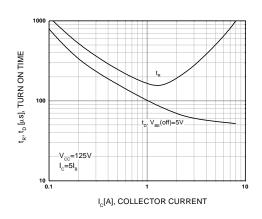


Figure 4. Turn On Time

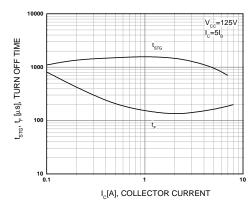


Figure 5. Turn Off Time

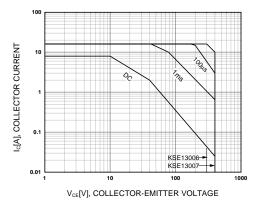


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)

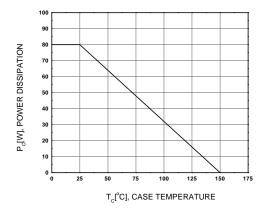
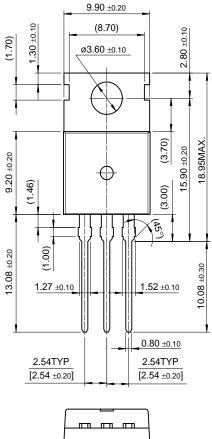
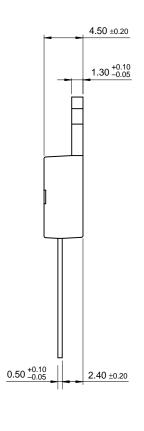


Figure 7. Power Derating

## **Package Demensions**

## TO-220





10.00 ±0.20

Dimensions in Millimeters

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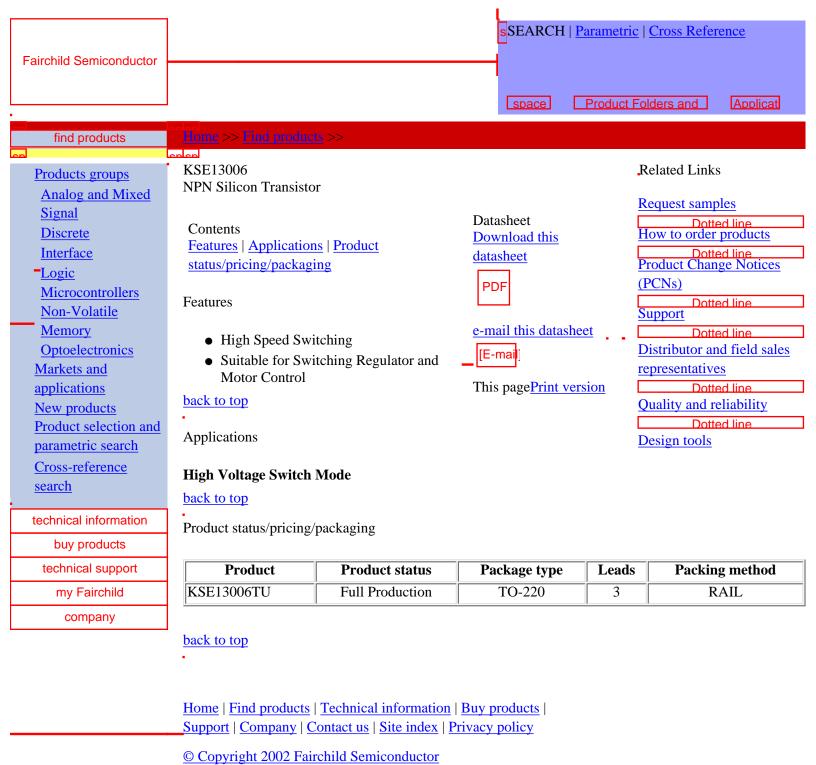
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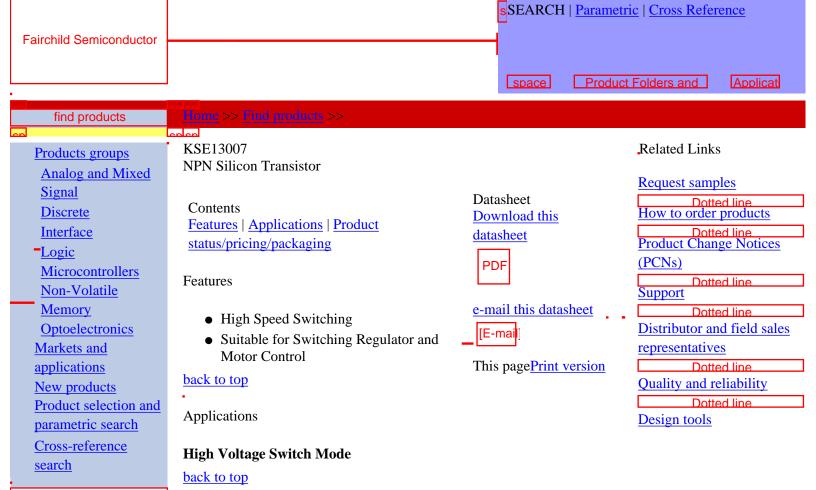
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Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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Product	Product status	Pricing*	Package type	Leads	Packing method
KSE13007H1SM	Full Production	\$0.62	TO-220	3	BULK
KSE13007SMTU	Full Production	\$0.62	TO-220	3	RAIL
KSE13007H2SM	Full Production	\$0.62	TO-220	3	BULK
KSE13007SM	Full Production	\$0.62	TO-220	3	BULK
KSE13007H2SMTU	Full Production	\$0.62	TO-220	3	RAIL
KSE13007H1SMTU	Full Production	\$0.62	TO-220	3	RAIL
KSE13007H3SM	Full Production	\$0.62	TO-220	3	BULK

<sup>\* 1,000</sup> piece Budgetary Pricing

Product status/pricing/packaging

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